Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# 2SA1020

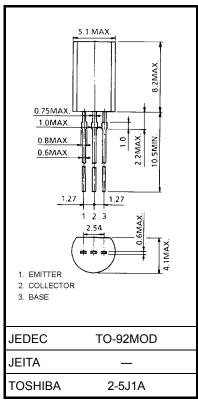
# Power Amplifier Applications Power Switching Applications

- Low Collector saturation voltage:  $V_{CE}$  (sat) = -0.5 V (max) ( $I_{C}$  = -1 A)
- High-speed switching:  $t_{stg} = 1.0 \mu s$  (typ.)
- Complementary to 2SC2655

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	$V_{CBO}$	-50	V	
Collector-emitter voltage	$V_{CEO}$	-50	V	
Emitter-base voltage	$V_{EBO}$	-5	V	
Collector current	IC	-2	Α	
Collector power dissipation	PC	900	mW	
Junction temperature	Tj	150	°C	
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.36 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

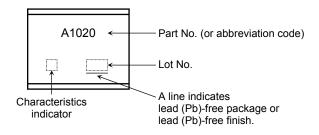


## Electrical Characteristics (Ta = 25°C)

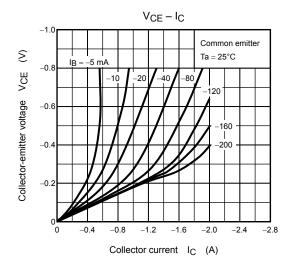
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	urrent	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-1.0	μΑ
Emitter cut-off cur	rrent	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-1.0	μА
Collector-emitter	breakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-50	_	—	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -0.5 A	70	_	240	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -1.5 A	40	_	_	
Collector-emitter	saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = -1 A, I <sub>B</sub> = -0.05 A	_	_	-0.5	V
Base-emitter satu	ration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = -1 A, I <sub>B</sub> = -0.05 A	_	_	-1.2	V
Transition frequen	псу	f <sub>T</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -0.5 A	_	100	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	_	40	_	pF
Switching time	Turn-on time	t <sub>on</sub>	Output 20 μs Input $\stackrel{\text{B2}}{\rightarrow}$	_	0.1	_	
	Storage time	t <sub>stg</sub>	$I_{B2} \xrightarrow{I_{B1}} V_{CC} = -30 \text{ V}$		1.0	_	μS
	Fall time	t <sub>f</sub>	-I <sub>B1</sub> = I <sub>B2</sub> = 0.05 A DUTY CYCLE ≤ 1%		0.1	_	

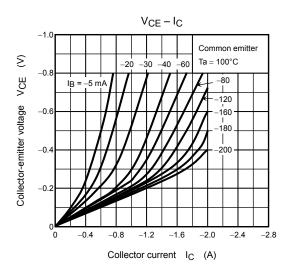
Note:  $h_{FE(1)}$  classification O: 70 to 140, Y: 120 to 240

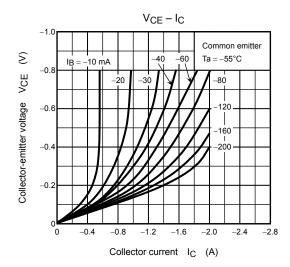
## Marking

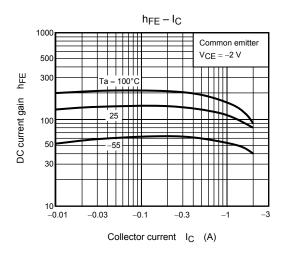


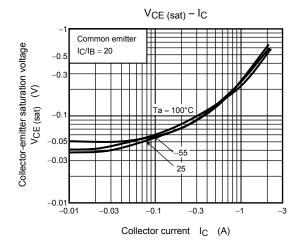
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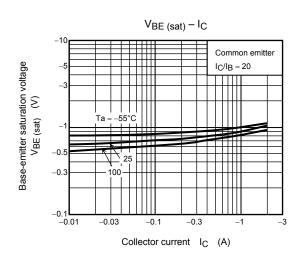




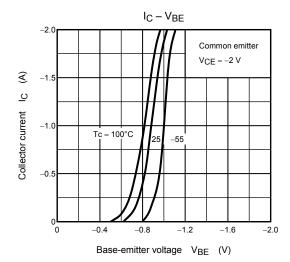


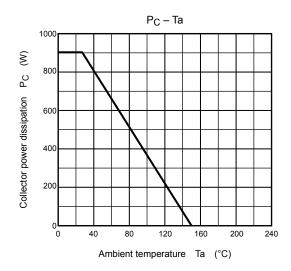


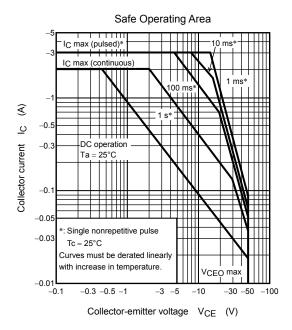




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